

STTH802-Y

Automotive ultrafast recovery diode

Features

- Very low conduction losses
- Negligible switching losses
- Low forward and reverse recovery time
- High junction temperature
- AEC-Q101 qualified

Description

The STTH802-Y uses ST's new 200 V planar Pt doping technology, and is specially suited for switching mode base drive and transistor circuits.

Packaged in DPAK, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection for automotive application.

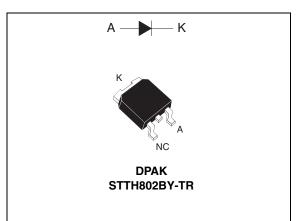


Table 1.Device summary

Symbol	Value
I _{F(AV)}	8 A
V _{RRM}	200 V
T _{j (max)}	175 °C
V _F (typ)	0.8 V
t _{rr} (typ)	17 ns

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1 Characteristics

Table 2. Absolute ratings (limiting values at $T_i = 25$ °C, unless otherwise specified)

Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive peak reverse voltage	200	V	
I _{F(RMS)}	Forward rms current	Forward rms current		
I _{F(AV)}	Average forward current, $\delta = 0.5$	T _c = 145 °C	8	А
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms Sinusoidal}$		100	А
T _{stg}	Storage temperature range		-65 to + 175	°C
Тj	Maximum operating junction temperature range	-40 to + 175	°C	

Table 3.Thermal parameters

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	3.2	°C/W

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _B ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V _V			6	μA
'R` ′	neverse leakage current	$T_j = 125 \text{ °C}$ $V_R = V_{RRM}$		6	60	μΑ	
V_(2)	$V_F^{(2)}$ Forward voltage drop $T_j = 25 \text{ °C}$ $T_j = 150 \text{ °C}$ $I_F = 8 \text{ A}$	T _j = 25 °C	1 _ 9 A		0.95	1.05	V
YF`'			0.8	0.90	v		

1. Pulse test: t_p = 5 ms, δ < 2 %

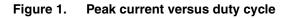
2. Pulse test: t_p = 380 µs, δ < 2 %

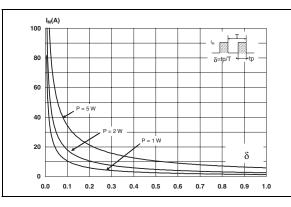
To evaluate the conduction losses use the following equation: P = 0.73 x $I_{F(AV)}$ + 0.021 $I_{F}^{2}(RMS)$

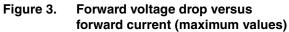


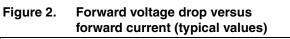
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
+	Reverse recovery time	$I_F = 1 \text{ A, } dI_F/dt = -50 \text{ A/}\mu\text{s},$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$		25	30	ns
t _{rr}		$\label{eq:lf} \begin{array}{l} I_F = 1 \mbox{ A, } dI_F/dt = -100 \mbox{ A/}\mu s, \\ V_R = 30 \mbox{ V, } T_j = 25 \mbox{ °C} \end{array}$		17	22	
I _{RM}	Reverse recovery current	$I_F = 8 \text{ A}, \text{ d}I_F/\text{d}t = -200 \text{ A}/\mu\text{s},$ $V_R = 160 \text{ V}, \text{ T}_j = 125 \ ^\circ\text{C}$		5.5	7	А
t _{fr}	Forward recovery time	$\label{eq:FF} \begin{array}{l} I_{F} = 8 \ A, \ dI_{F}/dt = 50 \ A/\mu s \\ V_{FR} = 1.1 \ x \ V_{Fmax}, \ T_{j} = 25 \ ^{\circ}C \end{array}$		150		ns
V _{FP}	Forward recovery voltage	$I_F = 8 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s},$ $T_j = 25 ^\circ\text{C}$		1.5		V

Table 5.	Dynamic characteristics
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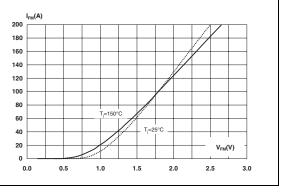


Figure 4. Relative variation of thermal impedance, junction to case, versus pulse duration

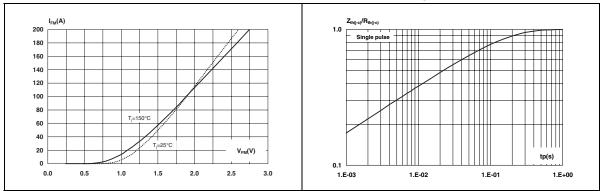
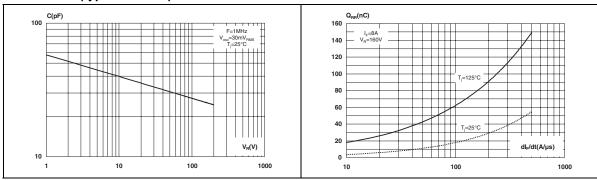
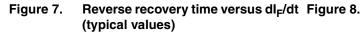


Figure 5. Junction capacitanceversus reverse applied voltage (typical values)

Figure 6. Reverse recovery charges versus dl_F/dt (typical values)





Peak reverse recovery current versus dl_F/dt (typical values)

T_j=125°C

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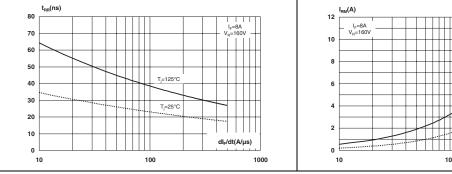
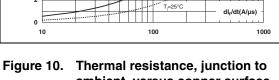
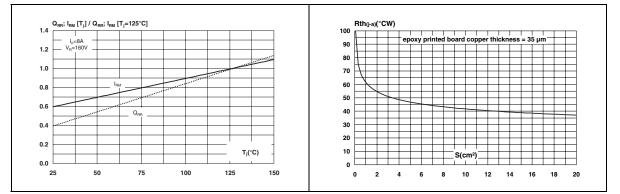


Figure 9. Dynamic parameters versus junction temperature



gure 10. Thermal resistance, junction to ambient, versus copper surface under tab





2 Package information

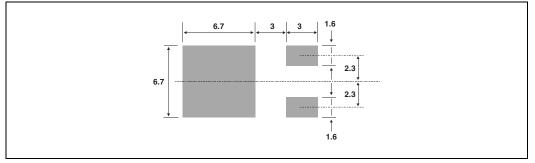
- Epoxy meets UL94, V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK[®] is an ST trademark.

Table 6. DPAK dimensions

		Dimensions				
	Ref.	Millim	neters	Inc	hes	
		Min.	Max.	Min.	Max.	
	Α	2.20	2.40	0.086	0.094	
Ę → A →	A1	0.90	1.10	0.035	0.043	
	A2	0.03	0.23	0.001	0.009	
	В	0.64	0.90	0.025	0.035	
	B2	5.20	5.40	0.204	0.212	
H B	С	0.45	0.60	0.017	0.023	
	C2	0.48	0.60	0.018	0.023	
	D	6.00	6.20	0.236	0.244	
	Е	6.40	6.60	0.251	0.259	
0.60 MIN.	G	4.40	4.60	0.173	0.181	
1	н	9.35	10.10	0.368	0.397	
₩ V2	L2	0.80	typ.	0.03	1 typ.	
	L4	0.60	1.00	0.023	0.039	
	V2	0°	8°	0°	8°	

Figure 11. Footprint (dimensions in mm)



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3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH802BY-TR	STTH802Y	DPAK	0.3 g	2500	Tape and reel

4 Revision history

Table 8.Document revision history

Date	Revision	Changes
10-Mar-2011	1	First issue.



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